

**66126**SINGLE/DUAL CHANNEL, HERMETICALLY SEALED  
OPTOCOUPLER, SIMILAR TO 4N55**Mii**OPTOELECTRONIC PRODUCTS  
DIVISION**Features:**

- DSCC Approved 8767902PX (Dual) and 9085401HPX (Single)
- 1500 Vdc isolation test voltage
- TTL and CMOS compatible
- 2 MHz bandwidth typical
- Faraday shield to provide high common mode rejection

**Applications:**

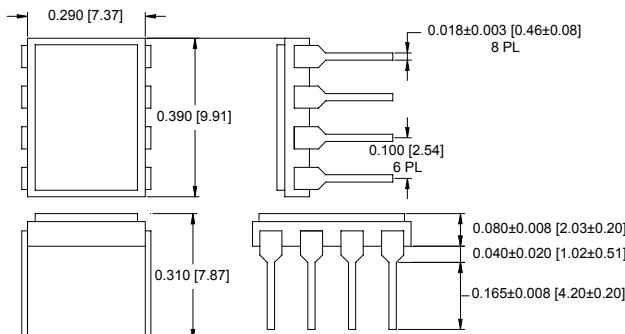
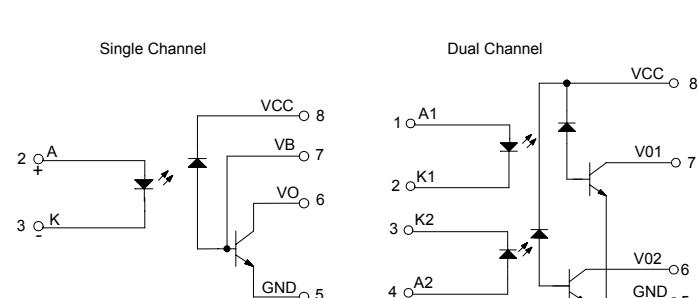
- Military and space
- Voltage level shifting
- Isolated receiver input
- Communication systems
- Medical systems

**DESCRIPTION**

The **66126** single/dual channel optocouplers utilize infrared LEDs optically coupled to high gain photon detectors. These unique optocouplers provide high switching speeds while providing high isolation (1500V/min) over the full military temperature range (-55° to +125°C). The 66126 is available in standard and MIL-PRF-38534 screened versions or tested to customer specifications.

**ABSOLUTE MAXIMUM RATINGS**

Storage Temperature.....	-65°C to +150°C
Operating Free-Air Temperature Range .....	-55°C to +125°C
Lead Solder Temperature.....	260°C for 10s (1.6mm below seating plane)
Peak Forward Input Current .....	40mA (1ms duration)
Average Forward Input Current .....	20mA
Input Power Dissipation .....	36mW
Reverse Input Voltage (each channel) .....	5V
Supply voltage - V <sub>CC</sub> (each channel) .....	7V (1 minute maximum)
Current - I <sub>O</sub> (each channel) .....	25mA
Output Power Dissipation (each channel)..(derate linearly at a rate of 1.4mW/°C above 100°C) .....	50mW
Output Voltage - V <sub>O</sub> (each channel) .....	7V
Base Current (each channel) .....	5mA

**Package Dimensions****Schematic Diagram**

ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]

66126

SINGLE/DUAL CHANNEL, HERMETICALLY SEALED OPTOCOUPLES, SIMILAR TO 4N55

**ELECTRICAL CHARACTERISTICS**T<sub>a</sub> = -55°C to 125°C unless otherwise specified.

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS	NOTE
Current Transfer Ratio	CTR	9	20		%	I <sub>F</sub> = 16mA, V <sub>O</sub> = 0.4V, V <sub>CC</sub> = 4.5V	1, 2
Output Leakage Current	I <sub>OH1</sub>		70	250	μA	I <sub>F</sub> = 250μA, V <sub>CC</sub> = V <sub>O</sub> = 18V I <sub>F</sub> (other channel) = 20mA	1
Logic High Output Current	I <sub>OH</sub>		20	100	μA	I <sub>F</sub> = 250μA, V <sub>CC</sub> = V <sub>O</sub> = 18V I <sub>F</sub> (other channel) = 20mA	1
High Level Output Current	I <sub>CCH</sub>		0.2	10	μA	I <sub>F</sub> = 0, V <sub>CC</sub> = 18V I <sub>F</sub> (other channel) = 20mA	1
Low Level Supply Current	I <sub>CCL</sub>		35	200	μA	I <sub>F1</sub> = I <sub>F2</sub> = 20mA, V <sub>CC</sub> = 18V	1
Input Forward Voltage	V <sub>F</sub>		1.5	1.8	V	I <sub>F</sub> = 20mA	1
Input Reverse Breakdown Voltage	BV <sub>R</sub>	3			V	I <sub>R</sub> = 10μA	1
Input-Output Insulation Leakage Current	I <sub>I-O</sub>			1.0	μA	V <sub>I-O</sub> = 1500Vdc, Relative Humidity = 45% t <sub>A</sub> = 25°C, t = 5s	3
Propagation Delay Time To High Output Level	t <sub>PLH</sub>		2	6	μs	I <sub>F</sub> = 16mA, V <sub>CC</sub> = 5V, R <sub>L</sub> = 8.2kΩ, C <sub>L</sub> = 50pF	1
Propagation Delay Time To Low Output Level	t <sub>PHL</sub>		0.4	2	μs	I <sub>F</sub> = 16mA, V <sub>CC</sub> = 5V, R <sub>L</sub> = 8.2kΩ, C <sub>L</sub> = 50pF	1

**TYPICAL CHARACTERISTICS**T<sub>a</sub> = 25°C, V<sub>CC</sub> = 5V Each Channel

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS	NOTE
Input Capacitance	C <sub>IN</sub>		120		pF	V <sub>F</sub> = 0, f = MHz	1
Capacitance (Input-Output)	C <sub>I-O</sub>		1.5		pF	f = 1MHz, V <sub>F</sub> = 0	1, 4
Capacitance (Input-Input)	C <sub>I-I</sub>		0.55		pF	f = 1MHz	
Input Diode Temperature Coefficient	$\frac{\Delta V_F}{\Delta T_A}$		-1.9		mV/°C	I <sub>F</sub> = 18mA	1
Resistance (Input-Output)	R <sub>I-O</sub>		10 <sup>12</sup>		Ω	V <sub>I-O</sub> = 500Vdc	1
Input-Input Insulation Leakage Current	I <sub>I-I</sub>		1		pA	Relative Humidity = 45% V <sub>I-I</sub> = 500Vdc, t = 5s	3
Common Mode Transient immunity at High Output Level	CM <sub>H</sub>	500	1000		V/μs	V <sub>CM</sub> = 50V P-P, R <sub>L</sub> = 8.2kΩ, I <sub>F</sub> = 0mA	1, 5
Common Mode Transient Immunity at Low Output Level	CM <sub>L</sub>	500	1000		V/μs	V <sub>CM</sub> = 50V P-P, R <sub>L</sub> = 8.2kΩ, I <sub>F</sub> = 16mA	1, 6

**NOTES:**

1. Each channel.
2. CURRENT TRANSFER RATIO is defined as the ratio of output collector current, I<sub>O</sub>, to the forward LED input current, I<sub>F</sub>, times 100%.
3. Measured between each input pair shorted together.
4. Measured between input pins shorted together and the output pins for that channel shorted together.
5. CM<sub>H</sub> is the maximum tolerable common mode transient to assure that the output will remain in a high logic state (ie. V<sub>O</sub> > @ .0V).
6. CM<sub>L</sub> is the maximum tolerable common mode transient to assure that the output will remain in a low logic state (ie. V<sub>O</sub> < 0.8V).

**RECOMMENDED OPERATING CONDITIONS:**

PARAMETER	SYMBOL	MIN	MAX	UNITS
Input Current, Low Level	I <sub>FL</sub>	0	2	μA
Supply Voltage	V <sub>CC</sub>	2.0	18	V

**SELECTION GUIDE**

PART NUMBER	PART DESCRIPTION
66126-001	Single Channel optocoupler tested over full military temperature range (-55° to +125°C)
66126-011	Single Channel optocoupler, Commercial (0° to 70°C)
66126-105	DSCC Dwg 5962-9085401HPX Single Channel Optocoupler
66126-002	Dual Channel optocoupler tested over full military temperature range (-55° to +125°C)
66126-012	Dual Channel optocoupler, Commercial (0° to 70°C)
66126-103	DSCC Dwg 5962-8767902PX Dual Channel Optocoupler

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибуторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

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Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ Р В 0015-002 и ЭС РД 009

**Офис по работе с юридическими лицами:**

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru  
moschip.ru\_4

moschip.ru\_6  
moschip.ru\_9